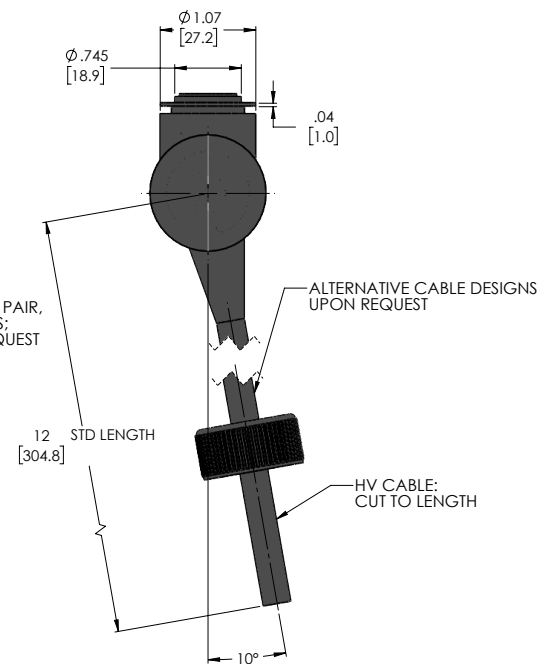
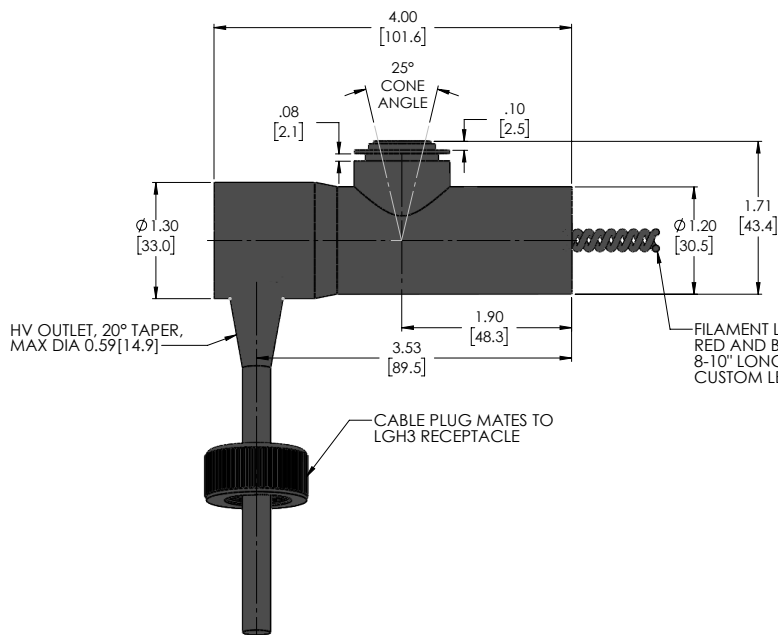
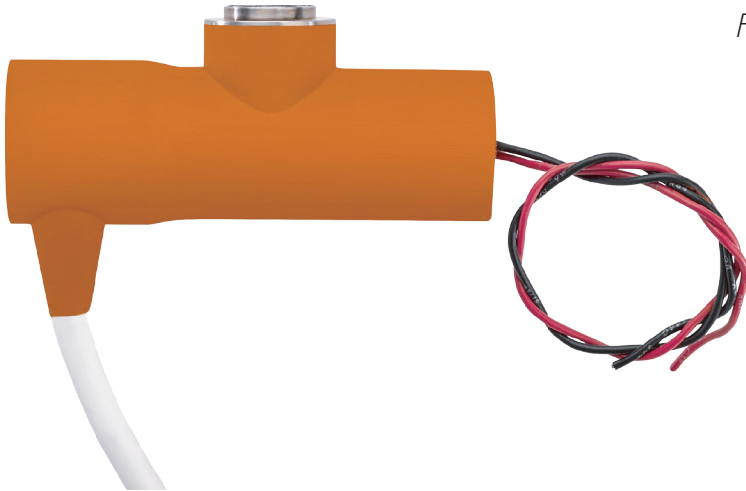


SILICON POTTED X-RAY TUBE

Our **Silicon Potted X-Ray Tube** is widely used for thickness gauging applications.

Features include:

- **An electron gun designed for long-term operation** at low kV and high mA.
- **An LGH3 cable ready to use** with your power supply.
- **Silicon potting** that provides high voltage isolation and offers an increased surface area to mount to your heatsink.



SPECIFICATIONS

Polarity	Grounded Cathode
Max. Voltage	30kV ¹
Max. Power	12W ¹
Max. Filament Current	1.3A, 1.7A
Max. Anode Current	2mA-3mA
Focal Spot	1000μm
Beam Angle	25°, 40°
Window Thickness	127μm Beryllium ²
Target Material	W, Fe, Ag, Pd, Ti ³
Cooling	Heat sink on anode side, forced air 150CFM recommended
Safety	External heat sink available on anode side

¹ Refer to Figure 1 and 2 to determine optimal operational parameters.

² Artifact-Free Windows available upon request.

³ More target materials available upon request.

GENERAL

The customer is responsible for controlling the high voltage and filament current and designing the cooling system. Selecting an appropriate power supply is crucial to protect the X-ray tube from overcurrent and overvoltage. Sufficient cooling is required when operating the X-ray tube. Failure to do so may damage the tube and radiation protection, posing a hazard.

RADIATION PROTECTION

The customer is responsible for radiation protection and must ensure compliance with local regulatory requirements and limit values.

FIGURE 1 - 1.3mA Filament

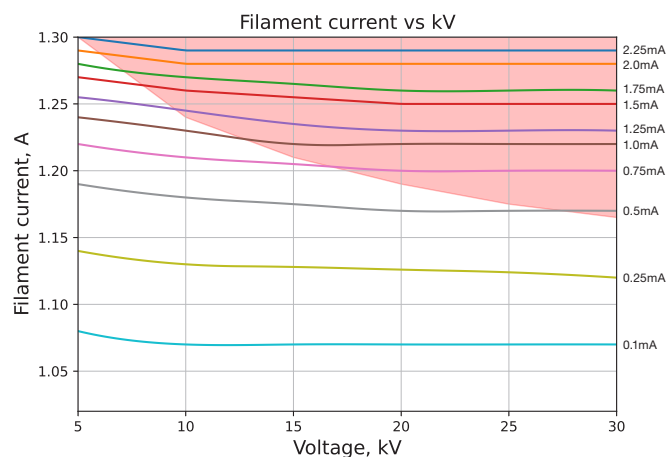
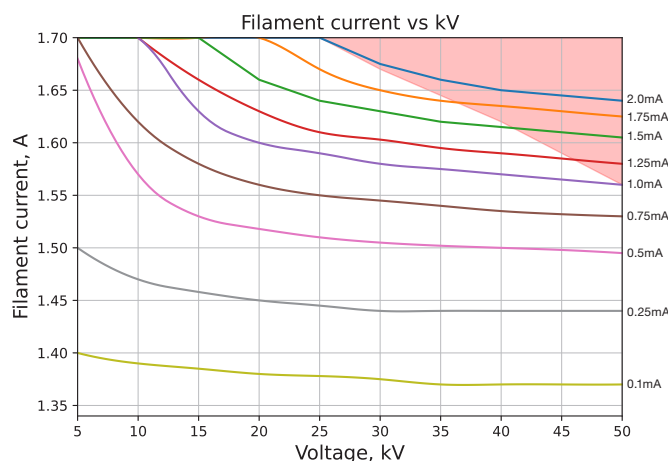


FIGURE 2 - 1.7mA Filament



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